MEMC 98-3052 (2512.2) PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application of Robert J. Falster Serial No. 10/038,084 Filed January 03, 2002 Confirmation No. 7363 Art Unit 2814

For SILICON ON INSULATOR STRUCTURE HAVING A LOW DEFECT DENSITY DEVICE LAYER AND A PROCESS FOR THE PREPARATION THEREOF

Examiner Anh D. Mai

June 28, 2004

AMENDMENT C

TO THE COMMISSIONER FOR PATENTS,

SIR:

In response to the Office action dated January 28, 2004, please consider the following remarks and arguments:

Remarks/Arguments begin on page 2 of this paper.

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10.00 DA

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